LED Shunt

The NUD4700 is an electronic shunt which provides a current bypass in the case of a single LED going into open circuit. LEDs are by nature quite fragile when subjected to transients and surge conditions. There are also many cases where high reliability of the LED lighting must be maintained such as headlights, lighthouses, bridges, aircraft, runways and so forth. In these cases the low cost addition of the NUD4700 will provide full assurance that an entire string of LEDs will not extinguish should one LED fail. NUD4700 is also applicable to other loads where circuit continuity is required. This device is designed to be used with 1 W LEDs (nominally 350 mA @ 3 V).

Features

- A Simple Two Terminal Device
- Automatically Resets Itself if the LED Heals Itself or is Replaced
- ON-State Voltage Typically 1 V
- OFF-State Current less than 250 μA
- Available with White Package
- SZ Prefix (black package only) for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

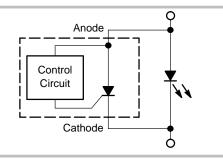
Typical Applications

- LEDs where Preventive Maintenance is Non Practical
- LED Headlights
- LEDs with High Reliability Requirements
- Crowbar Protection for Open Circuit Conditions
- Overvoltage Protection for Sensitive Circuits



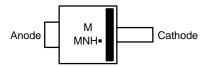
ON Semiconductor®

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MARKING DIAGRAM



M = Date CodeMNH = Device Code= Pb-Free Package

PIN FUNCTION DESCRIPTION

Pin	Description		
Anode	Positive Input Voltage to the Device		
Cathode	Negative Input Voltage to the Device		

ORDERING INFORMATION

Device	Package	Shipping [†]
NUD4700SNT1G	POWERMITE (Black)	3000/Tape & Reel
SZNUD4700SNT1G	POWERMITE (Black)	3000/Tape & Reel
NUD4700WSNT1G	POWERMITE (White)	3000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS (Maximum ratings are those, that, if exceeded, may cause damage to the device. Electrical Characteristics are not guaranteed over this range)

Rating	Symbol	Value	Unit
Peak Repetitive Off State Voltage (Anode to Cathode)	V_{DM}	-0.3 to 10	V
Average On–State Current, (T _A = 25°C), (Note 1) (Note 2)	I _{T(AVG)}	1.3 0.376	А
Thermal Resistance, Junction–to–Air (Note 1) (Note 2)	Q_JA	80 277	°C/W
Thermal Resistance, Junction-to-Lead	Q_JL	35	°C/W
Power Dissipation (T _A = 25°C) (Note 1) (Note 2)	P _{MAX}	1.56 0.45	W
Operating Temperature Range	T _J	-40 to 150	°C
Non-Operating Temperature Range	T _J	150	°C
Lead Temperature, Soldering (10 Sec)	T _L	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. Device mounted on minimum copper pad.

Critical Rate-of-Rise of Off State Voltage

(V_{pk} = Rated V_(BR), T_J = 125°C, Exponential Method)

ELECTRICAL CHARACTERISTICS (Unless otherwise noted: T_A = 25°C)

Characteristics	Symbol	Min	Тур	Max	Unit
Off–State Current (V _{Anode} = 5 V)	I _{LEAK}	_	100	250	μΑ
Breakdown Voltage (I _{BR} = 1 mA)	$V_{(BR)}$	5.5	-	7.5	V
Holding Current (V _{Anode} = 10 V, I _{initial} = 100 mA)	lн	-	6.0	12	mA
Latching Current (V _{Anode} = 10 V)	ΙL	_	35	70	mA
On–State Voltage $(I_T = 0.350 \text{ A})$ $(I_T = 0.750 \text{ A})$ $(I_T = 1.0 \text{ A})$	V _T	- - -	1.0 1.0 1.0	1.2 - -	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

dV/dt

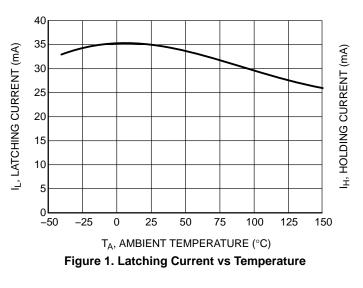
250

V/μs

Mounted onto a 1" x 1" square copper pad.
 Normally this device would be mounted on the same copper heat sink and adjacent to the LED. If the LED were to go open, then the NUD4700 shunt would now dissipate the power using the same copper heat sink. Since the NUD4700 has a voltage that is nominally 30% of the LED, then the power dissipation would be easily handled by the same heat sink as the LED.

TYPICAL PERFORMANCE CURVES

(T_A = 25°C unless otherwise noted)



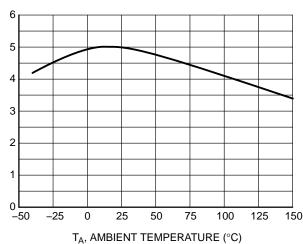


Figure 2. Holding Current vs Temperature

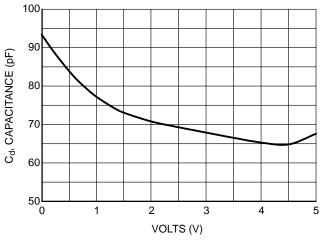


Figure 3. Capacitance vs Voltage

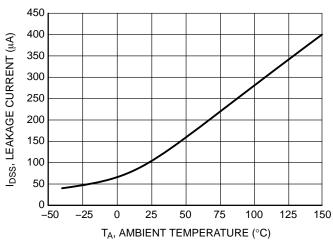


Figure 4. Leakage Current vs Temperature

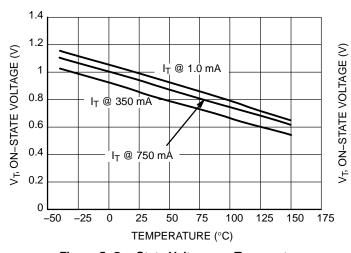


Figure 5. On-State Voltage vs. Temperature

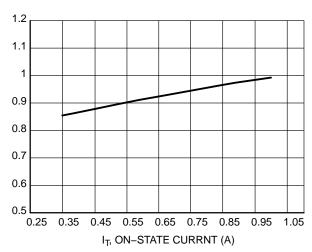
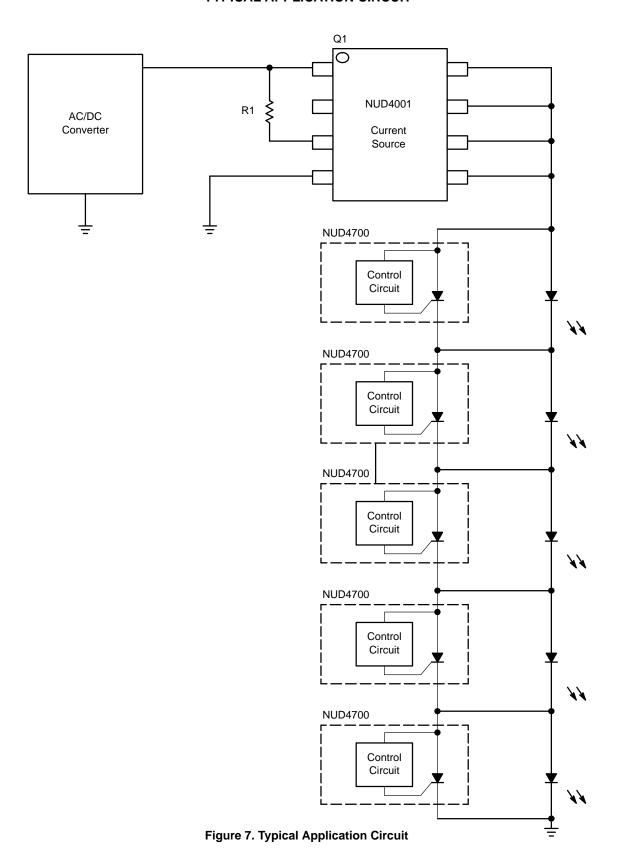


Figure 6. On-State Voltage vs. On-State Current (I_T) at 25°C

TYPICAL APPLICATION CIRCUIT



TYPICAL OPERATION WAVEFORMS

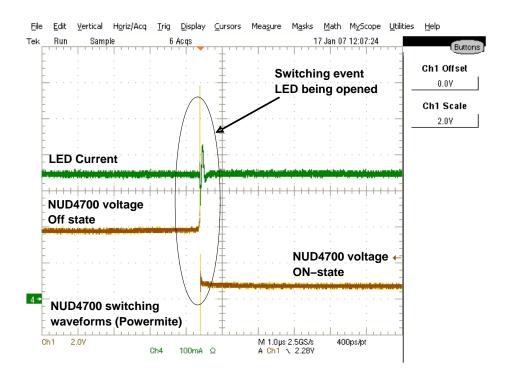


Figure 8. NUD4700 Switching Waveforms

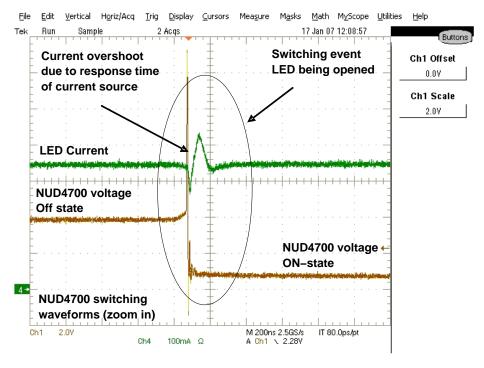


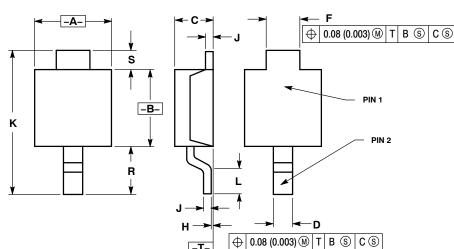
Figure 9. Zoom in of Figure 8

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POWERMITE CASE 457-04 ISSUE F

DATE 14 MAY 2013



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.

 - DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

	MILLIMETERS INC		HES	
DIM	MIN	MAX	MIN	MAX
Α	1.75	2.05	0.069	0.081
В	1.75	2.18	0.069	0.086
C	0.85	1.15	0.033	0.045
D	0.40	0.69	0.016	0.027
F	0.70	1.00	0.028	0.039
Н	-0.05	+0.10	-0.002	+0.004
J	0.10	0.25	0.004	0.010
K	3.60	3.90	0.142	0.154
L	0.50	0.80	0.020	0.031
R	1.20	1.50	0.047	0.059
S	0.50 REF		0.019	REF

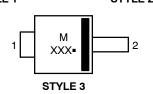
GENERIC MARKING DIAGRAMS*

STYLE 1: PIN 1. CATHODE 2. ANODE

STYLE 2: PIN 1. ANODE OR CATHODE CATHODE OR ANODE (BI-DIRECTIONAL) 2.

STYLE 3: PIN 1. ANODE 2. CATHODE

Μ М 2 2 XXX. XXX. STYLE 1 STYLE 2

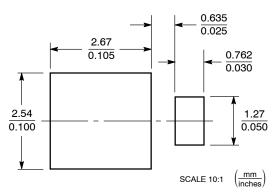


XXX = Specific Device Code = Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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